

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	8	amorphous adj spacer	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:21
S2	15	("5804499").URPN.	USPAT	OR	OFF	2005/06/02 16:49
S3	241	porous adj spacer	USPAT	OR	OFF	2005/06/02 16:49
S4	286	porous adj spacer	USPAT	OR	ON	2005/06/02 16:50
S5	59	porous adj spacer and thin adj layer	USPAT	OR	ON	2005/06/02 16:53
S6	2102	pores and dielectric adj material	USPAT	OR	ON	2005/06/02 16:53
S7	429	pores and dielectric adj material and transistor	USPAT	OR	ON	2005/06/02 16:54
S8	144	pores same dielectric adj material and transistor	USPAT	OR	ON	2005/06/02 16:56
S9	0	pores same dielectric adj material adj spacer and transistor	USPAT	OR	ON	2005/06/02 16:57
S10	10	pores same dielectric adj material same spacer and transistor	USPAT	OR	ON	2005/06/02 17:02
S11	1665	thin adj layer same spacer	USPAT	OR	ON	2005/06/02 17:49
S12	689	thin adj layer same spacer and transistor	USPAT	OR	ON	2005/06/02 17:50
S13	0	thin adj layer same pores same spacer and transistor	USPAT	OR	ON	2005/06/02 17:51
S14	14	thin adj layer and pores same spacer and transistor	USPAT	OR	ON	2005/06/02 18:09
S15	0	thin adj layer and porous adj spacer and transistor	USPAT	OR	ON	2005/06/02 18:09
S16	6	porous adj spacer and transistor	USPAT	OR	ON	2005/06/02 18:09
S17	14	("6528372" "6342450" "6316348" "6365451" "6297115" "6383951" "6194748").PN.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/06 15:49
S18	613	organic adj material same dielectric adj material	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 16:12
S19	9	organic adj material same porous adj dielectric adj material	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 17:08

EAST Search History

S20	1	organic adj solvent same porous adj dielectric adj material	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 17:38
S21	0	siocn same spacer	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 17:39
S22	0	sionc same spacer	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 18:09
S23	242	sion same spacer	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 18:09
S24	3	sion same spacer same carbon	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 18:32
S25	0	5nm same spacer same carbon	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 18:32
S26	1916	thin adj layer same spacer	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 18:38
S27	84	thin adj layer same spacer same nm	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 19:22
S28	34	porous adj dielectric same organic adj material	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/06 19:23
S29	1	oxygen adj plasma same spacers same porous	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/07 10:44
S30	1983	438/305.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:48
S31	1634	438/305.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 16:39

EAST Search History

S32	580	438/306.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:21
S33	1293	438/303.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:21
S34	1114	438/301.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:22
S35	555	438/299.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:22
S36	58	438/146.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:22
S37	45	438/76.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:22
S38	1322	438/592.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:22
S39	884	438/595.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 15:22
S40	78	(S30 S31 S32 S33 S34 S35 S36 S37 S38 S39) and porous	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/03/07 17:03
S41	7	(S30 S31 S32 S33 S34 S35 S36 S37 S38 S39) and porous near5 dielectric	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/03/07 17:03